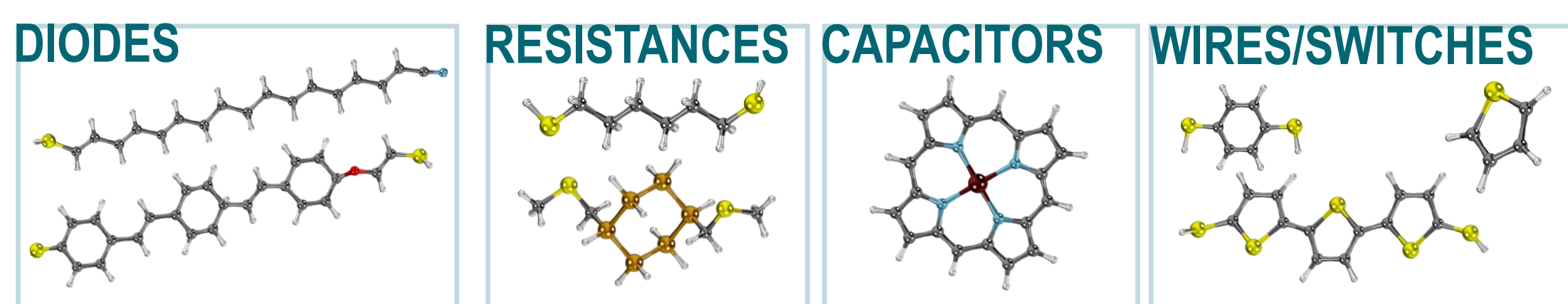
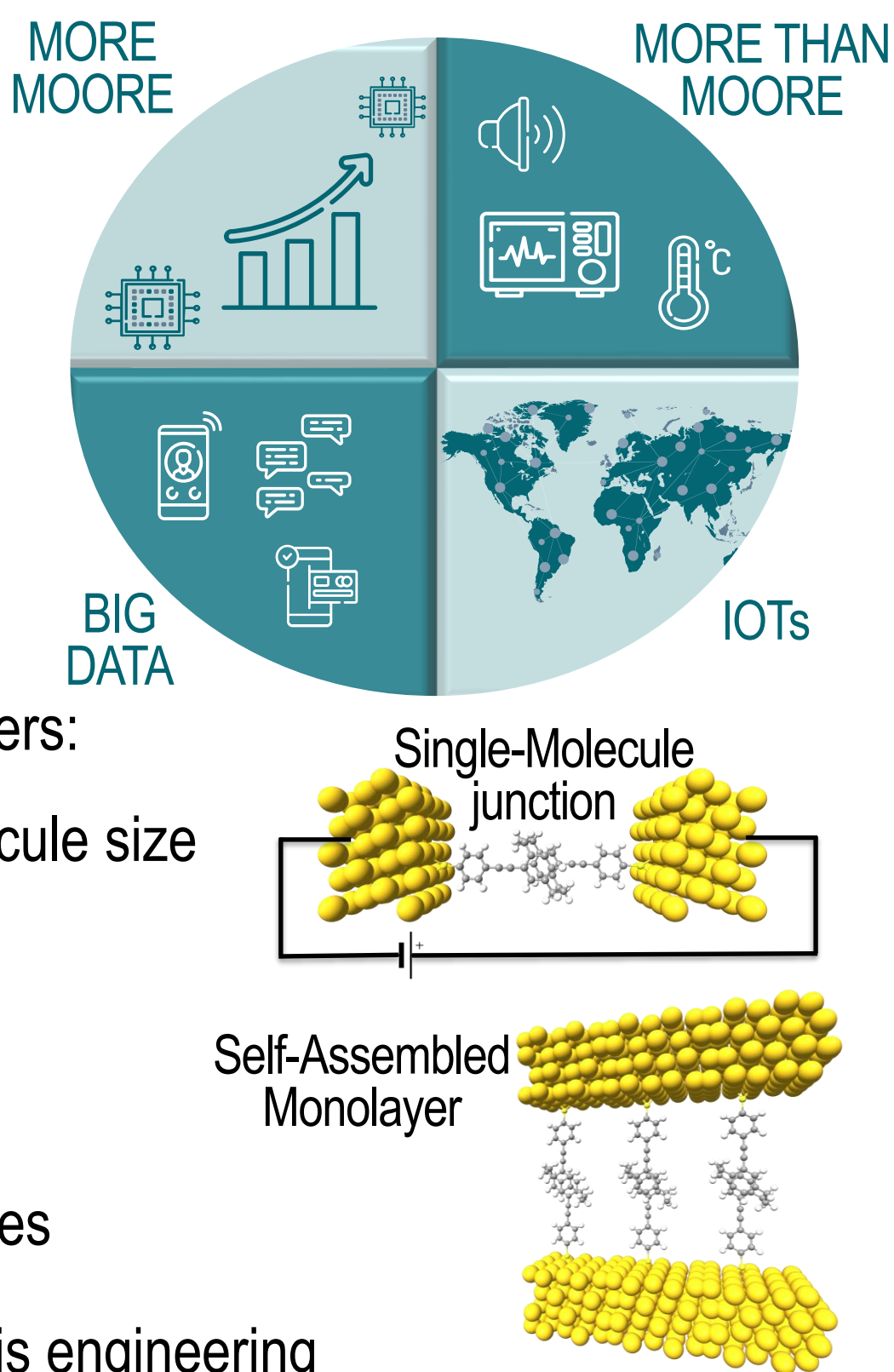


Research context and motivation

- Moore's law is at its ultimate limit, and the ubiquitous paradigm of the **Internet of Things (IOTs)**, the pervasive use of **Big Data** and **Artificial Intelligence (AI)** are driving an escalation in demand for heavily scaled, high performing, low-power systems, where **More than Moore (MtM)** paradigm with heterogeneous integration is becoming crucial.
- In this scenario, **MOLECULAR ELECTRONICS** offers:
 - ✓ **HIGH INTEGRATION**: intrinsic nanometric molecule size
 - ✓ **LOW POWER**: small intrinsic device parasitics
 - ✓ **ROOM TEMPERATURE USABILITY**
 - ✓ **CHEAP FABRICATION**: self-assembly techniques
 - ✓ **UNPARALLEL FLEXIBILITY**: chemical synthesis engineering
- The electronic properties of molecular devices can be engineered by chemical synthesis with vast degrees of freedom to implement **specific electronic functions**:

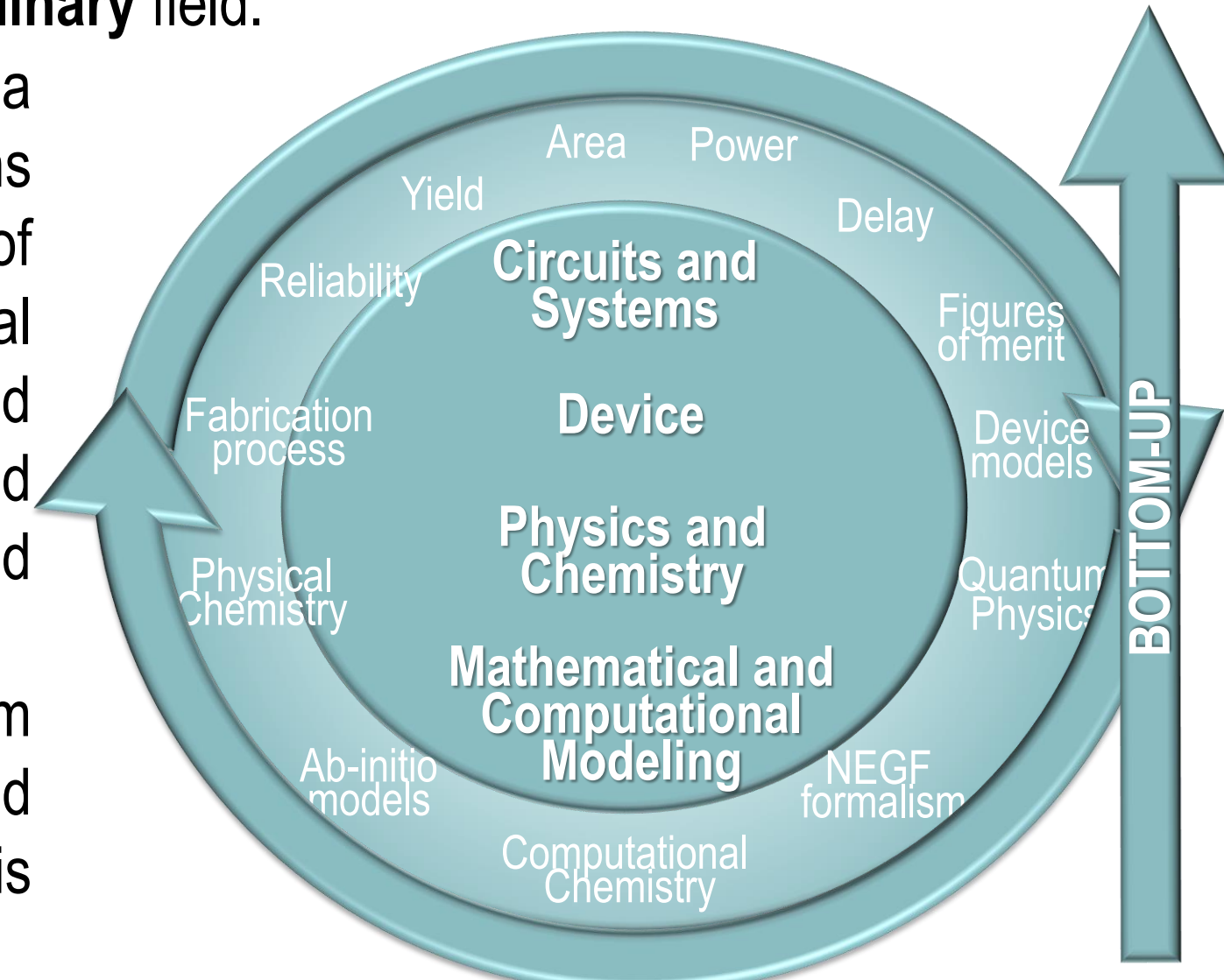


Addressed research questions/problems

- In the last two decades, a substantial effort has been spent to experimentally demonstrate and theoretically model single-molecule electronic devices. Nevertheless, molecular electronics is still in its **infancy stage** because of the following **open issues** addressed in this research:
 - **UNEFFECTIVE DEVICES AND CONTROL**: e.g., OPV7 single-molecule FET
 - Diagram of OPV7 FET structure and its I-V characteristics showing I_{OFF} , $DIBL$, V_{th} , $GIDL$, I_{ON}/I_{OFF} .
 - **LACK OF CIRCUITAL AND SYSTEM -LEVEL STUDIES**
 - Functionality
 - Power
 - Delay
 - Area
 - **DIFFICULTIES IN ON-CHIP INTEGRATION**
 - Massively parallel nanogap formation
 - Molecules anchoring
 - Different molecules for each device

Adopted methodologies

- Molecular electronics is a **multidisciplinary field**.
- In this research, we adopt a **delocalized perspective** that joins together the localized perspectives of mathematical and computational modeling, quantum and applied physics, physical chemistry, and electronics at the device, circuitual and system levels.
- A **bottom-up approach** starting from the chemical and physical levels and going up to the system level is employed in a **feedback way**.



Novel contributions and results

- In [3], we conceive an effective Back gate Biasing-based method for the **ON/OFF Current Ratio Enhancement of the single-molecule FET via the control of Destructive Quantum Interference (BBB-CURE-DQI)**.
 - Diagram of the device structure and energy level diagram showing HOMO, LUMO, and LUMO+1 levels.
 - Graphs showing log(Transmittivity) vs $E - E_F$ (eV) and Drain-Source Current vs Gate Voltage for different molecules (PCP, OPV7, OPE3).
 - Graphs showing Drain-Source Current vs abs(Drain-Source Voltage) for n-type and p-type PCP-FETs.
 - Timing diagram showing voltage levels for IN, pCp OUT, and OPV7 OUT.
- In [1], we develop a simple and effective **circuitual model for single-molecule FETs** that permits estimating the **area, power consumption and delay** of circuits and systems.
 - Diagram of a LUT-based circuit model for a layer of 7 parallel neurons.
 - Functional verification graph showing voltage vs time for different neurons.
- In [4], we investigate a **single-molecule amperometric AFB1 sensor** through DFT calculations to enable the **More Moore** paradigm in molecular-based chips.
- In [2], we investigate a **single-molecule device for Logic-in-Memory (LiM)** through DFT calculations. It may ease the on-chip integration since it implements logic and storage.

Future work

- Amelioration of the circuitual model for single-molecule devices
- Design of a programmable multipurpose single-molecule device
- STM-BJ or MBJ experiments

Submitted and published works

- [1] Mo, F., Spano, C., Ardesi, Y., Piccinini, G., Graziano, M. "Beyond-CMOS Artificial Neuron: A simulation-based exploration of the molecular-FET". IEEE TRANSACTIONS ON NANOTECHNOLOGY, vol. 20, pp. 903-911, December 2021
- [2] Spano, C., Mo, F., Ardesi, Y., Ruo Roch, M., Piccinini, G., Graziano, M. "Electronic Transport Study of Bistable Cr@C28 Single-Molecule Device for High-Density Data Storage Applications". 13th International Conference on Nanotechnology: Fundamentals and Applications (ICNFA'22), Praga (CZ), August 2022. ISBN: 978-1-990800-11-5.
- [3] Spano, C., Ardesi, Y., M., Piccinini, G., Graziano, M. "Enhancing the On/Off Current Ratio in Single-Molecule FET via Destructive Quantum Interference". IEEE TRANSACTIONS ON ELECTRON DEVICES, vol. 69, pp. 1-7, September 2022.
- [4] Mo, F., Spano, C., Ardesi, Y., Ruo Roch, M., Piccinini, G., Graziano, M. "Single-molecule Aflatoxin B1 Sensing via Pyrrole-based Molecular Quantum Dot". 22nd IEEE International Conference on Nanotechnology (IEEE-NANO 2022), Palma de Mallorca (ES), July 2022.

List of attended classes

- 01UDAPE – Technology for Nanoelectronic Systems (26/01/21, 6 CFU)
- 01TZFOQ – Engineering Empathy (06/07/21, 6 CFU)
- 01TCPRV – Nano and Molecular Electronics (15/09/21, 8 CFU)
- 01MLHKG – Microscopia a scansione di sonda per la fisica e l'ingegneria (03/22, 6 CFU)
- 01SZPKG – Introduzione alla microscopia elettronica (07/22, 4 CFU)
- 01SHORV – Nano and Quantum Computing (09/22, 8 CFU)
- 10 Soft-skills classes (01/21, 10 CFU)